

# HMC509LP5E

Data Sheet

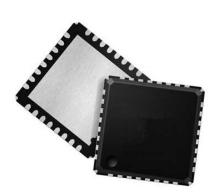
Hittite VCO,  $3.9 \rightarrow 4.4$  (Output 2) GHz,  $7.8 \rightarrow 8.8$  (Output 1) GHz, 32-Pin QFN

Manufacturers <u>Analog Devices, Inc</u>

Package/Case QFN-32

Product Type RF Integrated Circuits

RoHS Pb-free Halide free



Images are for reference only

Please submit RFQ for HMC509LP5E or Email to us: sales@ovaga.com We will contact you in 12 hours.

**RFO** 

### **General Description**

The HMC509LP5(E) is a GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC509LP5(E) integrates resonators, negative resistance devices, varactor diodes and feature a half frequency output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +13 dBm typical from a +5V supply. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

#### **Features**

Lifecycle

Dual Output: = 3.9 - 4.4 GHz

Pout: +13 dBm

Phase Noise: -115 dBc/Hz @100 kHz Typ.

No External Resonator Needed

QFN Leadless SMT Package, 25 mm<sup>2</sup>

## Application

VSAT Radio

Point-to-Point/Multi-Point Radio

Test Equipment & Industrial Controls

Military End-Use

#### **Related Products**



HMC3653LP3BE
Analog Devices, Inc
QFN-12



HMC441LP3E
Analog Devices, Inc
QFN-16



**HMC253AQS24** 

Analog Devices, Inc 24-SSOP (0.154, 3.90mm Width)



HMC948LP3E

Analog Devices, Inc LP3



HMC358MS8GE

Analog Devices, Inc MSOP-8



**HMC453ST89E** 

Analog Devices, Inc ST89E



### **HMC490**

Analog Devices, Inc SMD



HMC618ALP3E

Analog Devices, Inc QFN-16